Temperature Dependent Resistivity of Single Wall Carbon Nanotubes

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Nonchiral single wall carbon nanotubes with an "armchair" wrapping are theoretically predicted to be conducting, and high purity samples consisting predominantly of these tubes exhibit metallic behavior with an intrinsic resistivity which increases approximately linearly with temperature over a wide temperature range. Here we study the coupling of the conduction electrons to long wavelength torsional shape fluctuations, or twistons. A one dimensional theory of the scattering of electrons by twistons is presented which predicts an intrinsic resistivity proportional to the absolute temperature. Experimental measurements of the temperature dependence of the resistivity are reported and compared with the predictions of the twiston theory.

Since their discovery [1], there has been great interest in the electronic properties of carbon nanotubes. These are nanometer scale structures which can be understood as a single layer of graphite wrapped to form a cylindrical tube. This wrapping can be specified by two integers [M,N] which define the superlattice translation corresponding to an elementary orbit around the waist of the cylinder. Theory predicts that a single wall tube can exhibit insulating, semi-metallic or metallic behavior depending on the choice of the integers M and N. Using double laser ablation of Co- and Ni- doped graphite targets, a new catalytic route to the synthesis of these structures has been discovered which now allows the production of single-wall tubes [2]. This process produces bulk samples in which the [10,10] wrapping is predominant [3]. Tubes produced in this process self organize during deposition in a two dimensional triangular close packed lattice forming ropes (bundles of tubes), and ultimately mats (three dimensional samples of entangled ropes). The [10,10] tubes are predicted to be metallic, and experimental evidence that unoriented bulk samples as well as individual ropes are metallic has been presented in [2] and [4]. Here we study the intrinsic intra-tubule scattering processes responsible for the resistivities of these systems and then present experimental measurements of the temperature dependence of the resistivity. We find that the coupling of the low energy electronic states to thermal shape fluc*tuations* of the tubes leads naturally to a resistivity which scales linearly with temperature even deep into the low temperature regime. This behavior is quite unconventional for a metal, and is actually found experimentally in tubule-derived samples down to a crossover temperature $\approx 10\text{-}100 \text{ K}$. The effects of inter-tube coupling on the electronic and vibrational degrees of freedom responsible

for this effect are also briefly discussed below.

Here we will focus on the [N, N] "armchair" tubes, which band theory predicts to be metallic [5,6]. The low energy electronic structure of a single armchair tube consists of two pairs of one dimensional bands which cross the Fermi energy, and these can be described by the massless Dirac Hamiltonian:

$$H_e = \int dx \sum_{a,\sigma} i\hbar v_F (\psi^{\dagger}_{a\sigma+} \partial_x \psi_{a\sigma+} - \psi^{\dagger}_{a\sigma-} \partial_x \psi_{a\sigma-}).$$
(1)

Here $\psi_{a\sigma\pm}$ describes a right (left) moving electron with band index a = 1, 2 and spin $\sigma = \uparrow, \downarrow$. v_F is the Fermi velocity.

The electrical resistivity is determined by the dominant mechanism for backscattering of electrons. In the presence of short range direct electron electron interactions, the Hamiltonian (1) maps onto a two channel "Hubbard ladder" [7,8]. The backscattering of electrons due to repulsive electron electron interactions has been studied within this model [8,9], and one finds that above a crossover temperature it leads to a resistivity which scales linearly with temperature [8]. Here we consider a different and what we believe to be the dominant scattering process, namely the coupling between electrons and elastic deformations of the tubes. Our theory is the tubule analog to the Bloch Gruneisen (BG) theory of the scattering of a Bloch electron by the low energy long wavelength acoustic modes of the lattice [10]. For the tubules one finds that modes which twist the tube around its axis of symmetry locally compress and stretch bonds on the surface of the cylinder. We have found that these elastic deformations couple the right moving and left moving electronic states of (1) [6] and are thus effective at backscattering the electrons. However, the

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dispersions of both the electronic and lattice degrees of freedom are unusual for these structures which, as we discuss below, leads one naturally into a regime in which the modes responsible for the backscattering are always heavily thermally populated. We find that this implies a temperature dependent resistivity which is proportional to the absolute temperature even well below the nominal Debye temperature for this system, as observed experimentally, and in contrast to the usual BG theory of a conductor.

In a previous paper we have found that among the various possible low energy shape fluctuations of a tubule, only the twist provides an efficient backscattering mechanism for a conduction electron [6]. Thus we consider the scattering of electrons by thermally excited long wavelength "twistons", i.e. the acoustic torsional modes of the tubule. The coupling between electrons and twist is given by [6]

$$H_{e-t} = \lambda \int dx \sum_{a,\sigma} \nabla \theta \, \left(\psi_{a\sigma+}^{\dagger} \psi_{a\sigma-} + \text{h.c.} \right)$$
(2)

where $\theta(x)$ is the angle of the twist at a position x along the tubule. The coupling constant for an [N, N] tube is $\lambda = 3N\beta\hbar v_F/4\pi$, where $\beta = \partial \ln t/\partial \ln d$ describes the change in the bond hopping amplitude t with bond length d. The dynamics of long wavelength twistons may be described by the continuum elastic Lagrangian,

$$L_t = \frac{1}{2} \int dx \left[M_t \dot{\theta}^2 - C_t (\nabla \theta)^2 \right], \qquad (3)$$

where M_t is the moment of inertia per unit length of the tube and C_t is the twist modulus. The twiston dispersion is then $\omega_q = v_t q$ with $v_t = \sqrt{C_t/M_t}$.

The effect of twistons is rather unusual because they are the only long wavelength phonons which couple the right and left moving electrons in the Dirac spectrum for this system [6]. Unlike the phonon scattering in an ordinary metal, which requires a phonon with momentum $2k_F$, backscattering from twistons is not quantum mechanically frozen out at low temperatures. Twiston scattering introduces a *single* scattering event which scatters an electron from the right to left moving branch, as shown in the inset of Fig. 1. Moreover, since the momentum of a typical electron at temperature T is $k_B T/v_F$, the energy of the relevant twistons are of order $2k_BTv_t/v_F$. Since $v_t \ll v_F$, these phonons are always heavily thermally populated. The system is thus effectively in the "high temperature" limit for phonon scattering even at temperatures well below the Debye temperature.

The backscattering rate for an electron with momentum k may be computed from Fermi's golden rule to be

$$\frac{1}{\tau} = 2\pi\lambda^2 \int \frac{dq}{2\pi} \frac{v_t q}{C_t} \coth(\frac{\hbar\omega_q}{2k_B T}) \delta\left(v_F(2k-q)\right) \quad (4)$$

where we have ignored the small twiston energy $\hbar v_t q$ in the delta function. This rate is independent of k and linearly proportional to T. The one dimensional electrical resistivity is given by $\rho_{1D} = (h/e^2)/(8v_F \tau_{\rm tr})$, where for pure backscattering the transport lifetime is $\tau_{\rm tr} = \tau/2$. We thus find

$$\rho_{1D} = \frac{9}{32\pi^2} \frac{h}{e^2} \frac{\beta^2}{Nc_t} k_B T,$$
 (5)

where $c_t = C_t / N^3$ is independent of N.

While the parameters in our theory have not yet been measured for carbon nanotubes, they can be estimated using the corresponding quantities known for graphite. Based on the in plane shear modulus of graphite we estimate $c_t = 18 \text{eV}\text{\AA}$ [11]. This predicts a velocity $\hbar v_t = 0.09 \text{eV}\text{\AA}$ which is equal to the speed of the in plane transverse acoustic phonon of graphite. In addition, we estimate $\hbar v_F = 5.3 \text{eV}\text{\AA}$ and $\beta = 2.3$ [12]. For a rope of triangular close-packed [10,10] tubes with a lattice constant 17 Å, this leads to a temperature dependent contribution to the three dimensional rope resistivity with slope $d\rho_{3D}/dT = 0.005\mu\Omega \text{cm/K}$

Balents and Fisher have recently shown that Umklapp scattering due to electron-electron interactions also leads to a resistivity which is linear in temperature [8]. Whereas the twiston resistivity scales as 1/N, the Umklapp resistivity is proportional to $1/N^2$. Thus for sufficiently large tubes the lattice effects should dominate. Comparing the prefactors we estimate that for N = 10the two have comparable magnitudes, with the twiston resistivity larger by a factor of 4 [13].

The above discussion has focused on the resistivity of an isolated tube. This ignores three-dimensional effects for the dynamics of both the electrons and the phonons, which may be crucial for the correct interpretation of measurements on bundles (or "ropes") of tubes. At low frequency, twistons on neighboring tubes should be coupled elastically which leads to a gap in the twiston spectrum as $q \to 0$. This may be described within an Einstein model for the inter-tube twistons, with the dispersion relation $\omega_q = \sqrt{v_t^2 q^2 + \omega_0^2}$. The energy scale $\hbar \omega_0$ may be estimated by considering the corresponding phenomena in graphite and in crystalline C_{60} . In graphite the relevant zone boundary phonon has energy 4 meV [11], whereas the energy of librons in crystalline C_{60} span the range 2 - 6 meV [14].

Coherent tunneling of electrons between the tubes also destroys the nesting of the Fermi surface. Given the bandwidth W, a phonon with wavevector as large as $q \approx W/v_F$ is needed is needed to backscatter, so that at low temperature, direct backscattering can ultimately be frozen out over a large part of the Fermi surface. W is difficult to estimate, because it will depend on the details of the orientational registry between neighboring tubes. However, it is unlikely that it will be negligible for this system. Solid phases of C_{60} have an interball electronic bandwidth of order 0.5 eV [15]. In graphite tunneling between neighboring layers leads to two interlayer bandwidths, one of order 1 eV and one with a much narrower

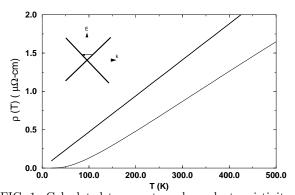


FIG. 1. Calculated temperature dependent resistivity due to twiston scattering. The upper bold curve is calculated for a one dimensional model for which $\rho \propto T$. Including three dimensional intertube effects in both the electron and twiston degrees of freedom we obtain the lower curve. which shows that the linear temperature dependence occurs in a three dimensional sample above relatively low crossover temperature. The inset shows the process in which an electron scatters from the right to left moving branch, emitting a long wavelength twiston.

width of order 10 meV. Electronic structure calculations within the local density approximation for a three dimensional lattice of [12,12] tubes have estimated a bandwidth of order 0.5 eV [16]. It is possible that because of the frustration of a five-fold symmetric [10,10] tube in a six-fold coordinated environment, the intertube bandwidth may be slightly narrower.

Our estimates of the scattering rates, and thus the resistivity due to twiston scattering may be generalized to include both of these effects. In Fig. 1 we plot the resistivity as a function of temperature calculated using our one-dimensional model, and recalculated including these three dimensional effects for the representative parameters $\omega_0 = 4$ meV and W = .5 eV. We find that the resistivity of the three dimensional system is then essentially linear for T > 100K. This is well below the effective Debye temperature for the twistons which is of order 1000 K. We find that in this system the one dimensional behavior can control the resistivity so long as $(v_t/v_F)W > \hbar\omega_0$ as seems likely in this system. The dynamics is then essentially one dimensional for $k_B T > \max(\hbar \omega_0, (v_t/v_F) W)$. We note that Umklapp scattering is suppressed for $k_BT < W$. Due to the small ratio $v_t/v_F \approx .02$, twiston scattering is more robust in the presence of inter tube coherence.

To test the above theory, it is clearly desirable to measure the electrical transport through a single isolated tube. However, to date, single tube transport has only been measured at very low temperature, where Coulomb charging effects dominate [17]. In Fig. 2 we present 4 different measurements of the temperature dependence of the electrical resistivity of nanotube ropes and unoriented bulk samples, all prepared as described in Ref. 2. The top curve in Fig. 2(a) is a 4-probe 1 KHz measurement on a bulk sample using silver paint contacts. Above about 200 K ρ increases linearly with temperature. This confirms and extends to 580 K the linear behavior previously observed up to 470 K [4]. The absolute value has little meaning since the tensor components are not separable, the material is very porous, and the effect of inter-rope contacts is unknown. The logarithmic derivative obtained from a linear fit in the interval 300 K < T < 580 K is 0.0008 K⁻¹. The lower curve is derived from a microwave absorption measurement on a few micrograms of similar material. The absolute value of ρ from this technique depends on the depolarization factor which is very difficult to estimate given the complex morphology, while the logarithmic derivative, 0.001 K⁻¹ is comparable to the 4-probe value.

Fig. 2(b) shows a 2-probe measurement of ρ_{\parallel} (described previously [4]) on several ropes in parallel. Again, linear behavior is observed over a wide temperature range, with a somewhat smaller logarithmic derivative, .0004 K⁻¹. 4-probe absolute ρ_{\parallel} measurements were performed at 300 K on similar samples and span the range 30 - 100 $\mu\Omega$ cm.

Fig. 2(c) shows a 4-probe measurement on a single 7 nm diameter rope with voltage contacts 500 nm apart. The room temperature resistivity is $90\mu\Omega cm$, which is consistent with the above measurement. The slope $d\rho/dT \approx .1\mu\Omega cm/K$.

These measurements clearly indicate metallic behavior at high temperatures with ρ increasing approximately linearly with temperature. Taking $\rho_{\parallel}(300 \text{ K}) = 90\mu\Omega\text{cm}$, and assuming the T dependence of the bulk samples is dominated by $\rho_{\parallel}(T)$, we infer the absolute slope from the first three measurements. For the bulk, microwave and 2probe rope measurements we thus find $d\rho/dT \sim .07, .09$ and $.04\mu\Omega cm/K$. While the four measurements of the slope agree to within a factor of 2.5, they are a factor of 8-20 larger than the twiston scattering theory prediction. Part of this discrepancy could arise from the presence of non-metallic tubes in the ropes. Recent electron diffraction measurements [3] on similar materials have indicated that more than 50% of the tubes in a rope are chiral and hence insulating [5,6]. The presence of such "dead" tubes would lead to an overestimate of the rope's intrinsic resistivity. In addition, variations in the electron tunneling matrix elements between different tubes in a rope - which depend sensitively on the relative orientation of the tubes - could lead to an additional source of backscattering which is not present for a single tube. In order to distinguish such effects from the intrinsic resistivity of a single tube a high temperature transport measurement on a single tube is clearly desirable.

It is striking that in addition to the high temperature linear resistivity, all the experimental measurements show an upturn in the resistivity at low temperature. The onset of this low temperature behavior depends on the sample morphology and can be as low as 10K for single ropes. It has been suggested that this upturn may signal a condensation of the system to form a collective charge- or spin- density wave ground state in the tube [8]

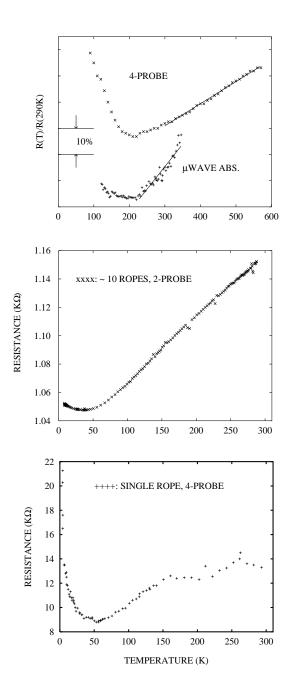


FIG. 2. Measured resistivities of samples of carbon nanotubes. (a) Bulk material: The top curve is a 4-probe measurement. The lower curve is measured by microwave absorption. (b) 2-probe measurement on several ropes in parallel. (c) 4-terminal measurement of a single rope

[9]. However, the observed dependence of this crossover on the sample morphology and quality suggests that disorder or other three dimensional effects may actually control this low temperature behavior. It will be important to carry out further experimental work to understand the origin of this nonconducting low temperature behavior.

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